NSN 5961-01-363-4672

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4672 **Inclosure Material:** Glass **Overall Length:** 0.098 inches **Overall Height:** 0.050 inches **Overall Width:** 0.098 inches **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 22.0 reverse voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset and 100.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Ribbon terminal cut at 45.0 degrees angle is the cathode **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No